Diode Semiconductor Device - Page 1 of 1



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	e Material:
Glass	_
Overall L	-
0.300 inc	
	I Length:
1.050 inc	
	Diameter:
0.140 inc	
	g Method:
Terminal	
Features	s Provided:
Hermetic	ally sealed case
Semicor	nductor Material:
Silicon	
Voltage	Rating In Volts Per Characteristic:
50.0 rev	erse voltage, peak
Current	Rating Per Characteristic:
5.00 mici	roamperes forward current, average peak
Maximu	m Operating Tempurature Per Measurement Point:
175.0 de	grees celsius ambient air
Termina	I Type And Quantity:
2 uninsul	ated wire lead
Specific	ation Data:
80131-re	lease6377 professional/industrial association specification
Shelf Lif	e:
N/a	
Unit Of N	Measure:
Demilita	rization:
No	
Fiig:	